

Crystal structure and low-temperature magnetic properties of $R_mM\text{In}_{3m+2}$ compounds ($M=\text{Rh}$ or Ir ; $m=1,2$; $R=\text{Sm}$ or Gd)

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We have synthesized the series of compounds $R\text{MIn}_5$ and $R_2M\text{In}_8$ in single crystal form, where $R=\text{Sm}$ or Gd and $M=\text{Rh}$ or Ir . These materials form in tetragonal derivatives of the Cu_3Au structure $R\text{In}_3$. Measurements of magnetic susceptibility, electrical resistivity, and low-temperature heat capacity are reported. These compounds order antiferromagnetically at low temperature ($T_N < 45$ K) and their low-temperature magnetic properties remain nearly unaltered compared to their SmIn_3 and GdIn_3 cubic relatives. The present data are compared to the magnetic properties of the isostructural $(\text{Ce},\text{Nd})(\text{Rh},\text{Ir})\text{In}_5$ and $(\text{Ce},\text{Nd})_2(\text{Rh},\text{Ir})\text{In}_8$ compounds, and the validity of de Gennes scaling as a function of rare earth in a given structure is discussed.

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I. INTRODUCTION

Recently, a new series of $R_mM\text{In}_{3m+2}$ tetragonal variants of the Cu_3Au -structure compounds for $M=\text{Rh}$ or Ir , $m=1,2$; and $R=\text{light rare earth}$ have become a particularly relevant area of research since the discovery of a new class of heavy-fermion superconductors for some of the Ce-based compounds.¹⁻³ The $R_mM\text{In}_{3m+2}$ tetragonal structures can be viewed as m layers of $R\text{In}_3$ units stacked sequentially along the c axis with intervening layers of $M\text{In}_2$ (Ref. 4) and unconventional magnetic and superconducting behavior have been reported for CeRhIn_5 (Ref. 1) and CeIrIn_5 .² The first one is an antiferromagnet at ambient pressure ($T_N \approx 3.8$ K and $\gamma \approx 400$ mJ/mol K²),¹ and presents an unconventional evolution to a superconducting state for $P > P_c \approx 16$ kbars where superconductivity sets in at $T_c \approx 2$ K. CeIrIn_5 shows ambient-pressure heavy-fermion superconductivity at $T_c \approx 0.4$ K with a Sommerfeld coefficient of $\gamma \approx 720$ mJ/mol K².² The $m=2$ variants of these Ce-based compounds include an antiferromagnetic ground state ($T_N \approx 2.8$ K and $\gamma \approx 400$ mJ/mol K²) for Ce_2RhIn_8 , while Ce_2IrIn_8 remains a heavy-fermion paramagnet to 50 mK, with no evidence for a phase transition ($\gamma \approx 700$ mJ/mol K²).³

It has been suggested that the reduced spatial dimensionality and magnetic anisotropy resulting from the quasi-two-dimensional structure of these compounds may control the nature of their heavy-fermion ground states.^{1,3} Furthermore, studies of NdMIn_5 and Nd_2MIn_8 analogs for $M=\text{Rh}$ or Ir suggest that crystal-field effects (CEF's) and related magnetic anisotropy play an important role in the evolution of the magnetic properties within these series.⁵ Therefore studies of the magnetic properties through the rare earths for $R_mM_n\text{In}_{3m+2n}$ ($M=\text{Rh}$ or Ir) appear to be a promising investigation. The Pr-based homologues are nonmagnetic singlet ground-state systems and a detailed CEF analysis of these materials will be given elsewhere.⁶

In the present work, we report magnetic susceptibility, electrical resistivity, and heat-capacity measurements on $(\text{Gd},\text{Sm})M\text{In}_5$ and $(\text{Gd},\text{Sm})_2M\text{In}_8$ single crystals, for $M=\text{Rh}$ or Ir . Each orders antiferromagnetically with $T_N \lesssim 45$ K. Comparisons to their cubic relative $(\text{Gd},\text{Sm})\text{In}_3$ suggest

that the insertion of $M\text{In}_2$ layers along the c axis in $(\text{Gd},\text{Sm})M\text{In}_5$ and $(\text{Gd},\text{Sm})_2M\text{In}_8$ ($M=\text{Rh}$ or Ir) only weakly affects the low-temperature magnetic ground state for the tetragonal variants. The data for the Ce and Nd-based homologues are also included to help the discussion.

II. EXPERIMENT

Single crystalline samples of the $(\text{Gd},\text{Sm})M\text{In}_5$ and $(\text{Gd},\text{Sm})_2M\text{In}_8$ ($M=\text{Rh}$ or Ir) compounds were grown from the melt in In flux as described previously.¹ Typical crystal sizes were 1×1 cm \times several mm. The tetragonal HoCoGa_5 ($m=1$) (Ref. 4) and Ho_2CoGa_8 ($m=2$) (Ref. 7) structure types and phase purity were confirmed by x-ray powder diffraction, and the crystal orientation was determined by the usual Laue method. The lattice parameters a and c for the studied compounds are given in Table I. Lattice constants for the nonmagnetic variants LaMIn_5 and La_2MIn_8 are also included for reference. Specific-heat measurements were per-

TABLE I. Experimental parameters for $(\text{Gd},\text{Sm})M\text{In}_5$, $(\text{Gd},\text{Sm})_2M\text{In}_8$ ($M=\text{Rh}$ or Ir), and $(\text{Gd},\text{Sm})\text{In}_3$.

	a Å	c Å	T_N K	μ_{eff} μ_B	θ_p K
GdIrIn_5	4.622(4)	7.413(8)	42	7.9(1)	≈ -64
Gd_2IrIn_8	4.615(4)	12.034(7)	41	8.2(1)	≈ -75
GdRhIn_5	4.609(4)	7.444(7)	40	8.0(1)	≈ -69
Gd_2RhIn_8	4.604(4)	12.060(9)	40	7.4(1)	-73
SmIrIn_5	4.634(4)	7.446(7)	14.3		
Sm_2IrIn_8	4.626(4)	12.088(7)	14.2		
SmRhIn_5	4.618(4)	7.470(8)	15.0		
Sm_2RhIn_8	4.621(4)	12.106(9)	15.0		
LaIrIn_5	4.710(4)	7.625(6)			
La_2IrIn_8	4.703(4)	12.314(7)			
LaRhIn_5	4.672(4)	7.602(7)			
La_2RhIn_8	4.699(4)	12.336(7)			
GdIn_3	4.6068 ^a		$\approx 45^a$	8.2 ^a	$\approx -85^a$
SmIn_3	4.6265 ^a		$\approx 16^a$		

^aSee Ref. 7.

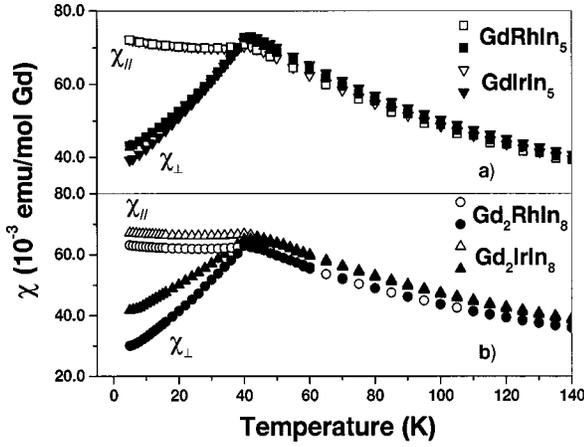


FIG. 1. Temperature dependence of the magnetic susceptibility, for applied field H along the c axis, $\chi_{||}$ (open symbols), and in the ab plane, χ_{\perp} (solid symbols), for Gd_mMIn_{3m+2} ($M=Rh$ or Ir) materials (a) for $m=1$ and (b) for $m=2$. The μ_{eff} and θ_p , obtained from Curie-Weiss law fitting for $T > 150$ K are given in Table I.

formed in a small-mass calorimeter that employs a quasi-adiabatic thermal relaxation technique.⁸ Samples used here ranged from 10 to 30 mg. Magnetization measurements were made in a Quantum Design dc superconducting quantum interference device and electrical resistivity was measured using a low-frequency ac resistance bridge and four-contact configuration.

III. RESULTS

Figures 1 and 2 present the temperature dependence of the magnetic susceptibility, for an applied field H along the c axis, $\chi_{||}$, and in the ab plane, χ_{\perp} , for the Gd_mMIn_{3m+2} and Sm_mMIn_{3m+2} materials, respectively. Each shows antiferromagnetic order, with $T_N < 45$ K. For the Gd-based materials the magnetic susceptibility is significantly anisotropic only below T_N showing a typical anisotropy of an antiferromagnet with an easy axis in the plane. The effective magnetic mo-

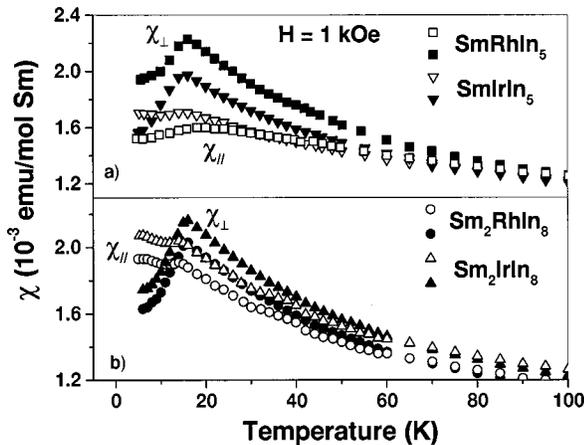


FIG. 2. Temperature dependence of the magnetic susceptibility, for applied field H along the c axis, $\chi_{||}$ (open symbols), and in the ab plane, χ_{\perp} (solid symbols), for Sm_mMIn_{3m+2} ($M=Rh$ or Ir) materials (a) for $m=1$ and (b) for $m=2$.

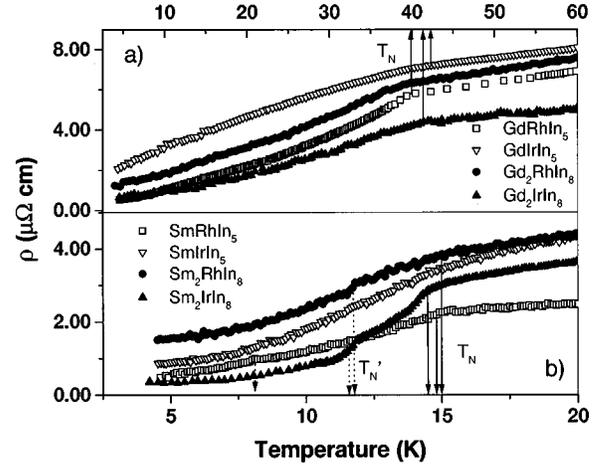


FIG. 3. Temperature dependence of the electrical resistivity for $(Gd,Sm)MIn_5$ and $(Gd,Sm)_2MIn_8$ ($M=Rh$ or Ir) single crystals. The solid arrows point out the Néel temperatures for the compounds while the dashed arrows mark possible extra features below T_N .

ment (μ_{eff}) and the paramagnetic Curie-Weiss temperatures (θ_p) obtained from Curie-Weiss law fits for $T > 150$ K for the Gd-based compounds are given in Table I. In the Sm-based case, the high-temperature magnetic anisotropy is probably associated with CEF in both ground $J=5/2$ and excited $J=7/2$ multiplet states of the Sm^{3+} ion.^{9,10} As typical in Sm-based materials, the high- T behavior of the inverse of magnetic susceptibility does not show a linear temperature dependence due to a Van Vleck contribution (which complicates the extraction of μ_{eff} and θ_p from the data).^{9,10}

The temperature dependence of the electrical resistivity for $(Gd,Sm)MIn_5$ and $(Gd,Sm)_2MIn_8$ ($M=Rh$ or Ir) single crystals is plotted in Fig. 3. The room-temperature value of the electrical resistivity varies between 20 and 30 $\mu\Omega$ cm and the high-temperature data show a metallic behavior for these compounds. At low temperatures, clear features can be seen at the respective ordering temperatures for all compounds. For the Sm-based homologues extra features also may be present in the data for $T < T_N$ for some of the compounds.

Figure 4 shows the specific heat divided by temperature (a) and the corresponding magnetic entropy (b) in the temperature range $2 \lesssim T \lesssim 20$ K, for $SmMIn_5$ and Sm_2MIn_8 ($M=Rh$ or Ir).

To calculate the magnetic entropy, the phonon contribution was estimated from the specific-heat data of $LaMIn_5$ (Refs. 1 and 2) and La_2MIn_8 (Ref. 3) ($M=Rh$ or Ir) and subtracted from the total specific heat of the magnetic compounds. The main peaks in C/T corresponding to the onset of antiferromagnetic order can be seen at $T_N = 14.18$ and 14.30 K for Sm_2IrIn_8 and $SmIrIn_5$, respectively, and at 15.00 K for both $SmRhIn_5$ and Sm_2RhIn_8 [Fig. 4(a)].

The Néel temperatures obtained from the specific-heat data are in very good agreement with the temperatures where the maximum in the magnetic susceptibility occurs (see Fig. 2).

For the Sm_2IrIn_8 , the antiferromagnetic transition at 14.18 K was found to be a first order transition with a latent heat of ~ 10 J/mol. However, no hysteresis was observed in the re-

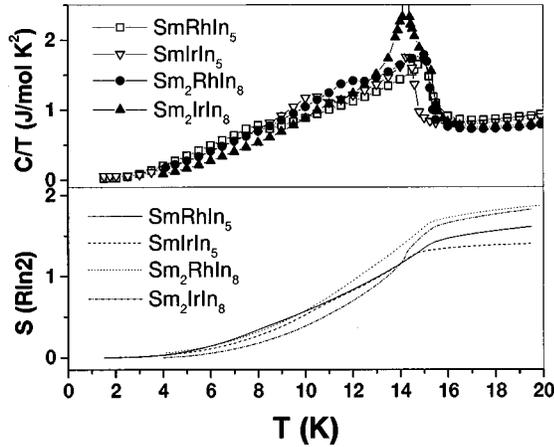


FIG. 4. Specific-heat data divided by temperature (a) and the corresponding magnetic entropy (b) in the temperature range $2 \lesssim T \lesssim 20$ K for $\text{Sm}M\text{In}_5$ and Sm_2MIn_8 ($M = \text{Rh}$ or Ir).

sistivity or magnetic susceptibility measurements as a function of temperature. The magnetic entropy recovered by T_N ranges between 1.4 and $1.8R \ln 2$ [Fig. 4(b)], suggesting that the magnetic order develops in a crystal-field doublet ground state with a nearby doublet excited state. Below T_N , a secondary feature in C_m/T was observed at 11.5 , 10.0 , 8.0 , and 12.0 K for Sm_2IrIn_8 , SmIrIn_5 , SmRhIn_5 , and Sm_2RhIn_8 , respectively [Fig. 4(a)]. These secondary peaks are coincident with features in the resistivity for some of the compounds (see Fig. 3). Similar extra transitions below T_N also have been reported for SmIn_3 and they have been interpreted as successive magnetic transitions associated with quadrupolar ordering.¹¹

IV. DISCUSSION

The cubic compounds $R\text{In}_3$ are antiferromagnets with $T_N \lesssim 50$ K (Ref. 9) and their T_N and θ_p values follow de Gennes scaling quite well, with the exception of CeIn_3 ,⁹ NdIn_3 and SmIn_3 , whose magnetic order develops in a Γ_8 quartet crystal-field ground state, present additional magnetic transitions below T_N .^{11–13} These complex magnetic states with successive magnet ordering arise due to the presence of magnetoelastic effects and both bilinear and quadrupolar exchange interactions.^{11–13}

Surprisingly, the insertion of $m M\text{In}_2$ layers along the c axis in $(\text{Gd}, \text{Sm})M\text{In}_5$ and $(\text{Gd}, \text{Sm})_2M\text{In}_8$ ($M = \text{Rh}$ or Ir) causes no significant changes in their Néel temperatures, whereas T_N shows a strong variation among the Ce- and Nd-based homologous.^{3,5} It has been reported that the magnetization easy axis for $(\text{Ce}, \text{Nd})M\text{In}_5$ and $(\text{Ce}, \text{Nd})_2M\text{In}_8$ ($M = \text{Rh}$ or Ir) is along the c axis,^{3,5} while the present data (see Figs. 1 and 2) suggest an easy axis in the ab plane for the $(\text{Gd}, \text{Sm})M\text{In}_5$ and $(\text{Gd}, \text{Sm})_2M\text{In}_8$ ($M = \text{Rh}$ or Ir) compounds. As we discuss below, this change in the direction of the magnetic easy axis may be related to a reduction through the rare earths in the competing anisotropic magnetocrystalline and crystal-field effects reported for Ce and Nd.^{3,5}

In order to discuss the evolution of the magnetic properties of the $RM\text{In}_5$ and $R_2M\text{In}_8$ ($M = \text{Rh}$ or Ir), we plot the

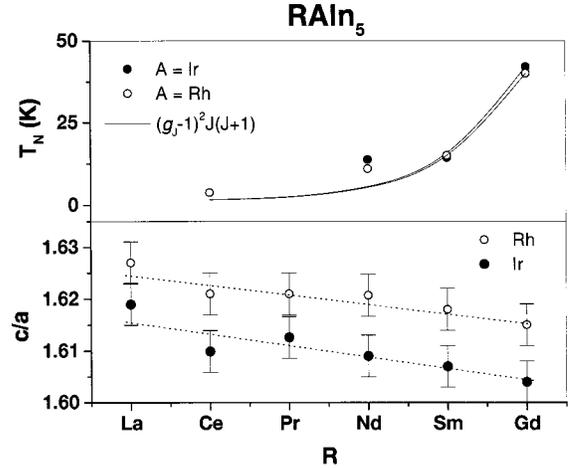


FIG. 5. T_N and c/a values plotted through the rare-earth series for the $RM\text{In}_5$ ($M = \text{Rh}$ or Ir) compounds. The solid lines are the de Gennes factor $[(g_J^2 - 1)][J(J+1)]$ for ground-state multiplet J of the rare earths normalized by the $\text{Gd}M\text{In}_5$ ($M = \text{Rh}$ or Ir) T_N values and the dashed lines are a guide for the eye.

T_N and c/a ratio (see also Table I) for $RM\text{In}_5$ ($R = \text{Ce}, \text{Nd}, \text{Sm}, \text{Gd}$; $M = \text{Rh}, \text{Ir}$) and $R_2M\text{In}_8$ ($R = \text{Ce}, \text{Nd}, \text{Sm}, \text{Gd}$; $M = \text{Rh}$ or Ir) in Figs. 5 and 6, respectively. Figure 7 shows the evolution of the Néel temperature for the homologous $RM\text{In}_5$ and $R_2M\text{In}_8$ ($R = \text{Ce}, \text{Nd}, \text{Gd}, \text{Sm}$; $M = \text{Rh}$ or Ir) compounds compared to their cubic $R\text{In}_3$ ($\text{Ce}, \text{Nd}, \text{Sm}, \text{Gd}$) relatives.

The solid lines in Figs. 5 and 6 are the de Gennes factor $(g_J^2 - 1)[J(J+1)]$ for ground-state multiplet J through the rare earths. If one normalizes the de Gennes line to the $\text{Gd}_mM\text{In}_{3m+2}$ ($M = \text{Rh}$ or Ir , $m = 1, 2$) T_N values, the Sm-based T_N values sit on the line but the T_N values for the Nd-based and the magnetic Ce-based compounds are above the line (see Figs. 5 and 6). In addition, the evolution of the Néel temperature for the homologous $RM\text{In}_5$ and $R_2M\text{In}_8$ compounds compared to their cubic $R\text{In}_3$ relatives, varies by

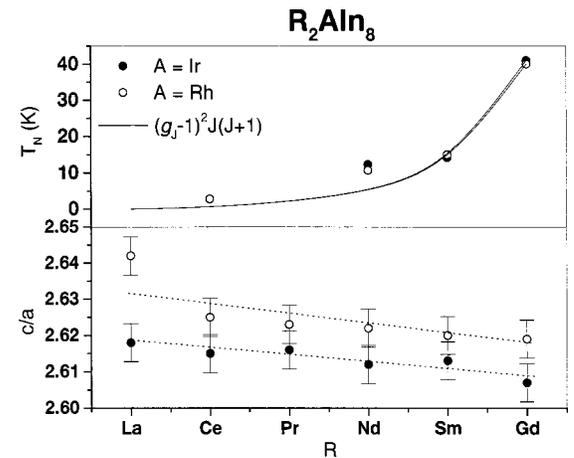


FIG. 6. T_N and c/a values plotted through the rare-earth series for the $R_2M\text{In}_8$ ($M = \text{Rh}$ or Ir) compounds. The solid lines are the de Gennes factor $[(g_J^2 - 1)][J(J+1)]$ of the rare earths normalized by the Gd_2MIn_8 ($M = \text{Rh}$ or Ir) T_N values and the dashed lines are a guide for the eye.

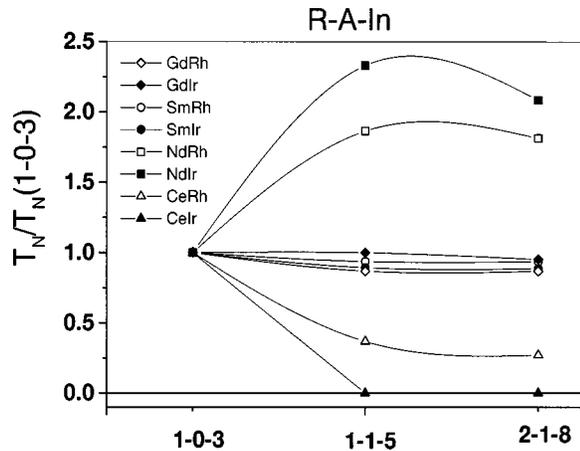


FIG. 7. Evolution of the normalized Néel temperatures for the Gd- and Sm-based compounds. For comparison, data for the homologous Ce- and Nd-based compounds and for cubic $R\text{In}_3$ ($R = \text{Ce, Nd, Sm, Gd}$), are also shown.

less than 10% for $R = \text{Gd}$ and Sm while T_N is raised by a factor of 2 for the Nd-based tetragonal variants and is suppressed completely ($M = \text{Ir}$) or to less than 0.5 of the CeIn_3 value ($M = \text{Rh}$) for the Ce-based homologous compounds (see Fig. 7).^{3,5}

De Gennes scaling¹⁴ does not take into account CEF, Kondo effects, and/or spatial dependence and anisotropic effects in the effective exchange parameter. Some of these effects are clearly present in the Ce-based and Nd-based homologues.^{1,3,5} Therefore it is not a surprise that the T_N values for the Ce-based and Nd-based homologues do not follow a de Gennes scaling. Furthermore, our data for Gd- and Sm-based compounds suggest that anisotropic and/or CEF effects may decrease along the rare-earth series. The Sm-based compounds (Sm^{3+} has $J = 5/2$, identical to Ce^{3+}) show smaller ratios $\chi_{\text{easy}}/\chi_{\perp\text{easy}}$ ranging between 1.05 and 1.30 (see Fig. 2) while these ratios range from 1.20 to greater than 2 for the Ce-based analogues.³ A possible explanation for this behavior may be related to the systematic decreasing

of c/a ratio through the rare-earth series (see Figs. 5 and 6) which may diminish the tetragonal character of the crystal-electric field and/or the magnetic anisotropy effects in the Sm case. The Gd-based compounds, which are expected to present small CEF due to the S character of the Gd^{3+} ($S = 7/2$, $L = 0$) ion, show only slight anisotropy in the magnetic susceptibility above T_N (see Fig. 1) and also small T_N evolution within the $R_m M_n \text{In}_{3m+2n}$ ($M = \text{Rh}$ or Ir , $m = 1, 2$; $n = 0, 1$) compounds. Therefore the absence or reduction of Kondo, CEF effects and/or magnetic anisotropy for the $(\text{Gd, Sm})M\text{In}_5$ and $(\text{Gd, Sm})_2M\text{In}_8$ ($M = \text{Rh}$ or Ir) compounds may cause their magnetic properties to be roughly the same as their cubic relatives GdIn_3 and SmIn_3 . Further investigation in the evolution of the crystal-field parameters and the character of the magnetic state for $RM\text{In}_5$ and $R_2M\text{In}_8$ including heaviest rare earths (e.g., $R = \text{Dy, Er,}$ or Yb) would be valuable in confirming our supposition.

V. CONCLUSIONS

We have reported a new series of Gd- and Sm-based antiferromagnetic ($T_N < 45$ K) compounds. Their low-temperature magnetic properties remain similar to their SmIn_3 and GdIn_3 cubic relatives. Comparisons among the present data and the magnetic properties of isostructural $(\text{Ce, Nd})(\text{Rh, Ir})\text{In}_5$ and $(\text{Ce, Nd})_2(\text{Rh, Ir})\text{In}_8$ and of de Gennes scaling as a function of rare earth in a given structure suggest that the reduction CEF effects and related magnetic anisotropy through the rare-earth series for the tetragonal variants may cause the magnetic properties of $(\text{Gd, Sm})M\text{In}_5$ ($(\text{Gd, Sm})_2M\text{In}_8$ ($M = \text{Rh}$ or Ir)) and their cubic relatives GdIn_3 and SmIn_3 to be nearly the same.

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